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Understanding [Embedded - DSP \(Digital Signal Processors\)](#)

[Embedded - DSP \(Digital Signal Processors\)](#) are specialized microprocessors designed to perform complex mathematical computations on digital signals in real-time. Unlike general-purpose processors, DSPs are optimized for high-speed numeric processing tasks, making them ideal for applications that require efficient and precise manipulation of digital data. These processors are fundamental in converting and processing signals in various forms, including audio, video, and communication signals, ensuring that data is accurately interpreted and utilized in embedded systems.

Applications of [Embedded - DSP \(Digital Signal Processors\)](#)

Details

Product Status	Obsolete
Type	SC140 Core
Interface	DSI, Ethernet, RS-232
Clock Rate	300MHz
Non-Volatile Memory	External
On-Chip RAM	1.436MB
Voltage - I/O	3.30V
Voltage - Core	1.10V
Operating Temperature	-40°C ~ 105°C (TJ)
Mounting Type	Surface Mount
Package / Case	431-BFBGA, FCBGA
Supplier Device Package	431-FCPBGA (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/msc8122tvt4800v

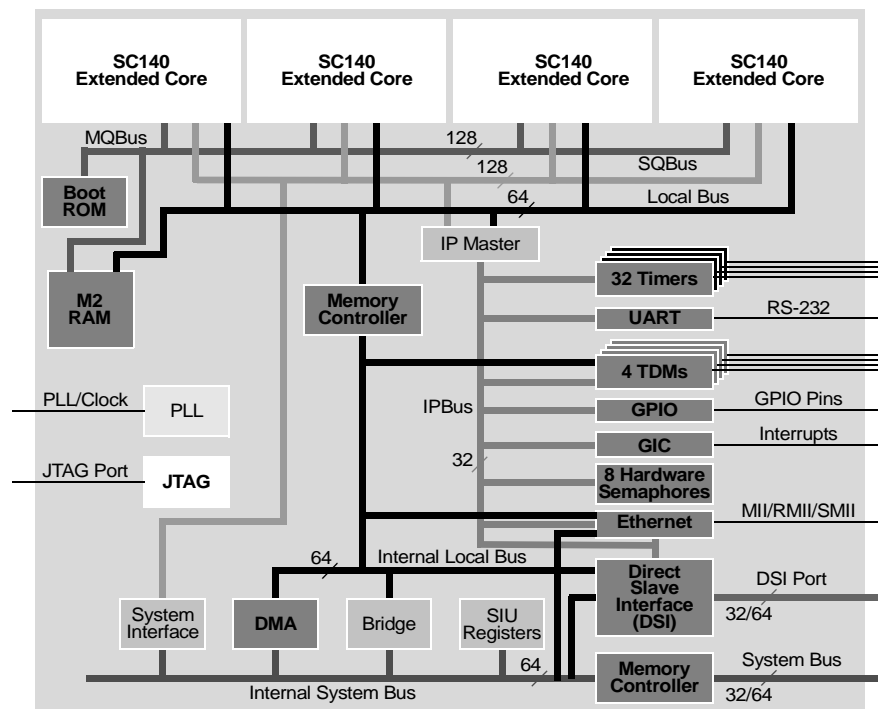
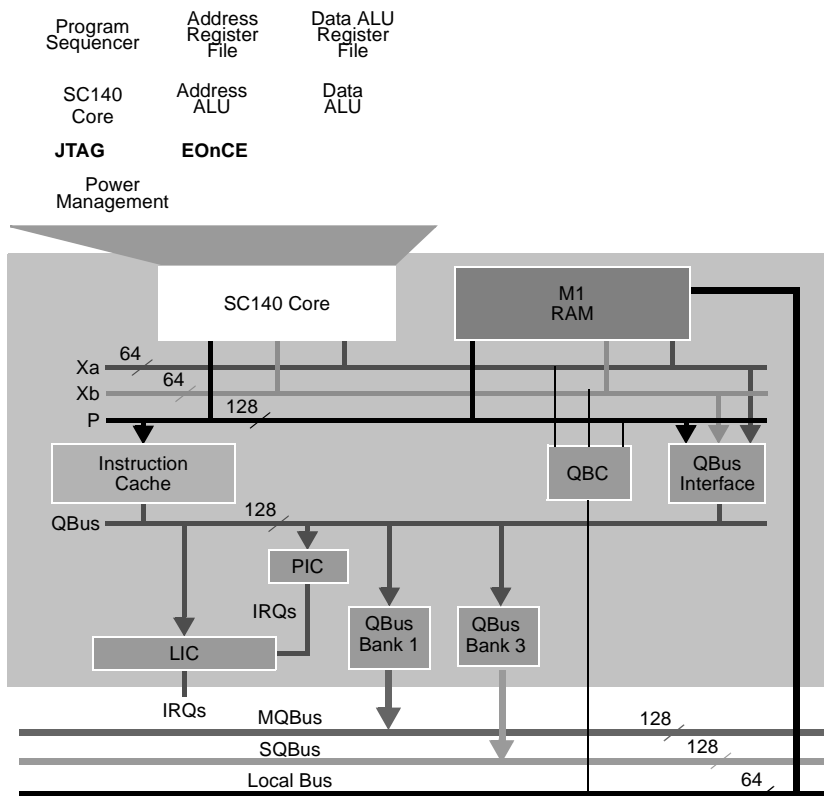


Figure 1. MSC8122 Block Diagram



Notes: 1. The arrows show the data transfer direction.
2. The QBus interface includes a bus switch, write buffer, fetch unit, and a control unit that defines four QBus banks. In addition, the QBC handles internal memory contentions.

Figure 2. StarCore SC140 DSP Extended Core Block Diagram

1 Pin Assignments

This section includes diagrams of the MSC8122 package ball grid array layouts and pinout allocation tables.

1.1 FC-PBGA Ball Layout Diagrams

Top and bottom views of the FC-PBGA package are shown in **Figure 3** and **Figure 4** with their ball location index numbers.

1.2 Signal List By Ball Location

Table 1 presents signal list sorted by ball number. -

Table 1. MSC8122 Signal Listing by Ball Designator

Des.	Signal Name	Des.	Signal Name
B3	V _{DD}	C18	GPIO1/TIMER0/CHIP_ID1/ $\overline{\text{IRQ5}}$ /ETHTXD1
B4	GND	C19	GPIO7/TDM3RCLK/ $\overline{\text{IRQ5}}$ /ETHTXD3
B5	GND	C20	GPIO3/TDM3TSYN/ $\overline{\text{IRQ1}}$ /ETHTXD2
B6	$\overline{\text{NMI_OUT}}$	C21	GPIO5/TDM3TDAT/ $\overline{\text{IRQ3}}$ /ETHRXD3
B7	GND	C22	GPIO6/TDM3RSYN/ $\overline{\text{IRQ4}}$ /ETHRXD2
B8	V _{DD}	D2	TDI
B9	GND	D3	EE0
B10	V _{DD}	D4	EE1
B11	GND	D5	GND
B12	V _{DD}	D6	V _{DDH}
B13	GND	D7	HCID2
B14	V _{DD}	D8	HCID3/HA8
B15	GND	D9	GND
B16	V _{DD}	D10	V _{DD}
B17	GND	D11	GND
B18	V _{DD}	D12	V _{DD}
B19	GPIO0/CHIP_ID0/ $\overline{\text{IRQ4}}$ /ETHTXD0	D13	GND
B20	V _{DD}	D14	V _{DD}
B21	V _{DD}	D15	V _{DD}
B22	GND	D16	GPIO31/TIMER3/SCL
C2	GND	D17	GPIO29/CHIP_ID3/ETHTX_EN
C3	V _{DD}	D18	V _{DDH}
C4	TDO	D19	GPIO4/TDM3TCLK/ $\overline{\text{IRQ2}}$ /ETHTX_ER
C5	$\overline{\text{SRESET}}$	D20	V _{DDH}
C6	GPIO28/UTXD/DREQ2	D21	GND
C7	HCID1	D22	GPIO8/TDM3RDAT/ $\overline{\text{IRQ6}}$ /ETHCOL
C8	GND	E2	TCK
C9	V _{DD}	E3	$\overline{\text{TRST}}$
C10	GND	E4	TMS
C11	V _{DD}	E5	$\overline{\text{HRESET}}$
C12	GND	E6	GPIO27/URXD/DREQ1
C13	V _{DD}	E7	HCID0
C14	GND	E8	GND
C15	GND	E9	V _{DD}
C16	GPIO30/TIMER2/TMCLK/SDA	E10	GND
C17	GPIO2/TIMER1/CHIP_ID2/ $\overline{\text{IRQ6}}$	E11	V _{DD}

Table 1. MSC8122 Signal Listing by Ball Designator (continued)

Des.	Signal Name	Des.	Signal Name
E12	GND	G6	HA17
E13	V _{DD}	G7	PWE0/PSDDQM0/PBS0
E14	GND	G8	V _{DD}
E15	GND	G9	V _{DD}
E16	V _{DD}	G10	IRQ3/BADDR31
E17	GND	G11	BM0/TC0/BNKSEL0
E18	GND	G12	ABB/IRQ4
E19	GPIO9/TDM2TSYN/IRQ7/ETHMDIO	G13	V _{DD}
E20	GPIO13/TDM2RCLK/IRQ11/ETHMDC	G14	IRQ7/INT_OUT
E21	GPIO10/TDM2TCLK/IRQ8/ETHRX_DV/ETHCRS_DV/NC	G15	ETHCRS/ETHRXD
E22	GPIO12/TDM2RSYN/IRQ10/ETHRXD1/ETHSYNC	G16	V _{DD}
F2	PORESET	G17	CS1
F3	RSTCONF	G18	BCTL0
F4	NMI	G19	GPIO15/TDM1TSYN/DREQ1
F5	HA29	G20	GND
F6	HA22	G21	GPIO17/TDM1TDAT/DACK1
F7	GND	G22	GPIO22/TDM0TCLK/DONE2/DRACK2
F8	V _{DD}	H2	HA20
F9	V _{DD}	H3	HA28
F10	V _{DD}	H4	V _{DD}
F11	GND	H5	HA19
F12	V _{DD}	H6	TEST
F13	GND	H7	PSDCAS/PGPL3
F14	V _{DD}	H8	PGTA/PUPMWAIT/PGPL4/PPBS
F15	ETHRX_CLK/ETHSYNC_IN	H9	V _{DD}
F16	ETHTX_CLK/ETHREF_CLK/ETHCLOCK	H10	BM1/TC1/BNKSEL1
F17	GPIO20/TDM1RDAT	H11	ARTRY
F18	GPIO18/TDM1RSYN/DREQ2	H12	AACK
F19	GPIO16/TDM1TCLK/DONE1/DRACK1	H13	DBB/IRQ5
F20	GPIO11/TDM2TDAT/IRQ9/ETHRX_ER/ETHTXD	H14	HTA
F21	GPIO14/TDM2RDAT/IRQ12/ETHRXD0/NC	H15	V _{DD}
F22	GPIO19/TDM1RCLK/DACK2	H16	TT4/CS7
G2	HA24	H17	CS4
G3	HA27	H18	GPIO24/TDM0RSYN/IRQ14
G4	HA25	H19	GPIO21/TDM0TSYN
G5	HA23	H20	V _{DD}

Table 1. MSC8122 Signal Listing by Ball Designator (continued)

Des.	Signal Name	Des.	Signal Name
H21	V _{DDH}	K15	V _{DD}
H22	A31	K16	TT2/ $\overline{\text{CS5}}$
J2	HA18	K17	ALE
J3	HA26	K18	$\overline{\text{CS2}}$
J4	V _{DD}	K19	GND
J5	HA13	K20	A26
J6	GND	K21	A29
J7	PSDAMUX/PGPL5	K22	A28
J8	BADDR27	L2	HA12
J9	V _{DD}	L3	HA14
J10	CLKIN	L4	HA11
J11	BM2/TC2/BNKSEL2	L5	V _{DDH}
J12	$\overline{\text{DBG}}$	L6	V _{DDH}
J13	V _{DD}	L7	BADDR28
J14	GND	L8	$\overline{\text{IRQ5/BADDR29}}$
J15	V _{DD}	L9	GND
J16	TT3/ $\overline{\text{CS6}}$	L10	GND
J17	PSDA10/PGPL0	L14	GND
J18	$\overline{\text{BCTL1/CS5}}$	L15	V _{DDH}
J19	GPIO23/TDM0TDAT/ $\overline{\text{IRQ13}}$	L16	GND
J20	GND	L17	GND
J21	GPIO25/TDM0RCLK/ $\overline{\text{IRQ15}}$	L18	$\overline{\text{CS3}}$
J22	A30	L19	V _{DDH}
K2	HA15	L20	A27
K3	HA21	L21	A25
K4	HA16	L22	A22
K5	$\overline{\text{PWE3/PSDDQM3/PBS3}}$	M2	HD28
K6	$\overline{\text{PWE1/PSDDQM1/PBS1}}$	M3	HD31
K7	$\overline{\text{POE/PSDRAS/PGPL2}}$	M4	V _{DDH}
K8	$\overline{\text{IRQ2/BADDR30}}$	M5	GND
K9	Reserved	M6	GND
K10	GND	M7	GND
K11	GND	M8	V _{DD}
K12	GND	M9	V _{DDH}
K13	GND	M10	GND
K14	CLKOUT	M14	GND

Table 1. MSC8122 Signal Listing by Ball Designator (continued)

Des.	Signal Name	Des.	Signal Name
M15	V _{DDH}	P12	V _{CCSYN}
M16	HBRST	P13	GND
M17	V _{DDH}	P14	GND
M18	V _{DDH}	P15	TA
M19	GND	P16	BR
M20	V _{DDH}	P17	TEA
M21	A24	P18	PSDVAL
M22	A21	P19	DP0/DREQ1/EXT_BR2
N2	HD26	P20	V _{DDH}
N3	HD30	P21	GND
N4	HD29	P22	A19
N5	HD24	R2	HD18
N6	PWE2/PSDDQM2/PBS2	R3	V _{DDH}
N7	V _{DDH}	R4	GND
N8	HWBS0/HDBS0/HWBE0/HDBE0	R5	HD22
N9	HBCS	R6	HWBS6/HDBS6/HWBE6/HDBE6/PWE6/PSDDQM6/PBS6
N10	GND	R7	HWBS4/HDBS4/HWBE4/HDBE4/PWE4/PSDDQM4/PBS4
N14	GND	R8	TSZ1
N15	HRDS/HRW/HRDE	R9	TSZ3
N16	BG	R10	IRQ1/GBL
N17	HCS	R11	V _{DD}
N18	CS0	R12	V _{DD}
N19	PSDWE/PGPL1	R13	V _{DD}
N20	GPIO26/TDM0RDAT	R14	TT0/HA7
N21	A23	R15	IRQ7/DP7/DREQ4
N22	A20	R16	IRQ6/DP6/DREQ3
P2	HD20	R17	IRQ3/DP3/DREQ2/EXT_BR3
P3	HD27	R18	TS
P4	HD25	R19	IRQ2/DP2/DACK2/EXT_DBG2
P5	HD23	R20	A17
P6	HWBS3/HDBS3/HWBE3/HDBE3	R21	A18
P7	HWBS2/HDBS2/HWBE2/HDBE2	R22	A16
P8	HWBS1/HDBS1/HWBE1/HDBE1	T2	HD17
P9	HCLKIN	T3	HD21
P10	GND	T4	HD1/DSISYNC
P11	GND _{SYN}	T5	HD0/SWTE

Table 1. MSC8122 Signal Listing by Ball Designator (continued)

Des.	Signal Name	Des.	Signal Name
W15	V _{DDH}	AA9	V _{DDH}
W16	HD33/D33/reserved	AA10	HD54/D54/ETHTX_EN
W17	V _{DDH}	AA11	HD52/D52
W18	HD32/D32/reserved	AA12	V _{DDH}
W19	GND	AA13	GND
W20	GND	AA14	V _{DDH}
W21	A7	AA15	HD46/D46/ETHTXT0
W22	A6	AA16	GND
Y2	HD7	AA17	HD42/D42/ETHRXD2/reserved
Y3	HD15	AA18	HD38/D38/reserved
Y4	V _{DDH}	AA19	HD35/D35/reserved
Y5	HD9	AA20	A0
Y6	V _{DD}	AA21	A2
Y7	HD60/D60/ETHCOL/reserved	AA22	A3
Y8	HD58/D58/ETHMDC	AB2	GND
Y9	GND	AB3	HD13
Y10	V _{DDH}	AB4	HD11
Y11	HD51/D51	AB5	HD8
Y12	GND	AB6	HD62/D62
Y13	V _{DDH}	AB7	HD61/D61
Y14	HD43/D43/ETHRXD3/reserved	AB8	HD57/D57/ETHRX_ER
Y15	GND	AB9	HD56/D56/ETHRX_DV/ETHCRS_DV
Y16	V _{DDH}	AB10	HD55/D55/ETHTX_ER/reserved
Y17	GND	AB11	HD53/D53
Y18	HD37/D37/reserved	AB12	HD50/D50
Y19	HD34/D34/reserved	AB13	HD49/D49/ETHTXD3/reserved
Y20	V _{DDH}	AB14	HD48/D48/ETHTXD2/reserved
Y21	A4	AB15	HD47/D47/ETHTXD1
Y22	A5	AB16	HD45/D45
AA2	V _{DD}	AB17	HD44/D44
AA3	HD14	AB18	HD41/D41/ETHRXD1
AA4	HD12	AB19	HD39/D39/reserved
AA5	HD10	AB20	HD36/D36/reserved
AA6	HD63/D63	AB21	A1
AA7	HD59/D59/ETHMDIO	AB22	V _{DD}
AA8	GND		

2.2 Recommended Operating Conditions

Table 3 lists recommended operating conditions. Proper device operation outside of these conditions is not guaranteed.

Table 3. Recommended Operating Conditions

Rating	Symbol	Value	Unit
Core and PLL supply voltage: • Standard — 400 MHz — 500 MHz • Reduced (300 and 400 MHz)	V_{DD} V_{CCSYN}	1.14 to 1.26 1.16 to 1.24 1.07 to 1.13	V V V
I/O supply voltage	V_{DDH}	3.135 to 3.465	V
Input voltage	V_{IN}	-0.2 to $V_{DDH}+0.2$	V
Operating temperature range: • Standard • Extended	T_J T_J	0 to 90 -40 to 105	°C °C

2.3 Thermal Characteristics

Table 4 describes thermal characteristics of the MSC8122 for the FC-PBGA packages.

Table 4. Thermal Characteristics for the MSC8122

Characteristic	Symbol	FC-PBGA 20 × 20 mm ⁵		Unit
		Natural Convection	200 ft/min (1 m/s) airflow	
Junction-to-ambient ^{1, 2}	$R_{\theta JA}$	26	21	°C/W
Junction-to-ambient, four-layer board ^{1, 3}	$R_{\theta JA}$	19	15	°C/W
Junction-to-board (bottom) ⁴	$R_{\theta JB}$	9		°C/W
Junction-to-case ⁵	$R_{\theta JC}$	0.9		°C/W
Junction-to-package-top ⁶	Ψ_{JT}	1		°C/W
Notes: <ol style="list-style-type: none"> 1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance. 2. Per SEMI G38-87 and JEDEC JESD51-2 with the single layer board horizontal. 3. Per JEDEC JESD51-6 with the board horizontal. 4. Thermal resistance between the die and the printed circuit board per JEDEC JESD 51-8. Board temperature is measured on the top surface of the board near the package. 5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1). 6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. 				

Section 3.5, *Thermal Considerations* provides a detailed explanation of these characteristics.

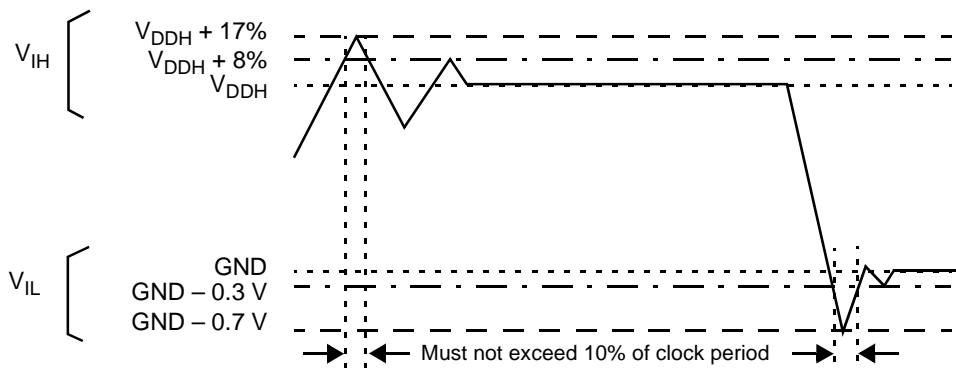


Figure 5. Overshoot/Undershoot Voltage for V_{IH} and V_{IL}

2.5 AC Timings

The following sections include illustrations and tables of clock diagrams, signals, and parallel I/O outputs and inputs. When systems such as DSP farms are developed using the DSI, use a device loading of 4 pF per pin. AC timings are based on a 20 pF load, except where noted otherwise, and a 50 Ω transmission line. For loads smaller than 20 pF, subtract 0.06 ns per pF down to 10 pF load. For loads larger than 20 pF, add 0.06 ns for SIU/Ethernet/DSI delay and 0.07 ns for GPIO/TDM/timer delay. When calculating overall loading, also consider additional RC delay.

2.5.1 Output Buffer Impedances

Table 6. Output Buffer Impedances

Output Buffers	Typical Impedance (Ω)
System bus	50
Memory controller	50
Parallel I/O	50
Note: These are typical values at 65°C. The impedance may vary by $\pm 25\%$ depending on device process and operating temperature.	

2.5.2 Start-Up Timing

Starting the device requires coordination among several input sequences including clocking, reset, and power. **Section 2.5.3** describes the clocking characteristics. **Section 2.5.4** describes the reset and power-up characteristics. You must use the following guidelines when starting up an MSC8122 device:

- $\overline{\text{PORESET}}$ and $\overline{\text{TRST}}$ must be asserted externally for the duration of the power-up sequence. See **Table 11** for timing.
- If possible, bring up the V_{DD} and V_{DDH} levels together. For designs with separate power supplies, bring up the V_{DD} levels and then the V_{DDH} levels (see **Figure 7**).
- CLKIN should start toggling at least 16 cycles (starting after V_{DDH} reaches its nominal level) before $\overline{\text{PORESET}}$ deassertion to guarantee correct device operation (see **Figure 6** and **Figure 7**).
- CLKIN must not be pulled high during V_{DDH} power-up. CLKIN can toggle during this period.

Note: See **Section 3.1** for start-up sequencing recommendations and **Section 3.2** for power supply design recommendations.

The following figures show acceptable start-up sequence examples. **Figure 6** shows a sequence in which V_{DD} and V_{DDH} are raised together. **Figure 7** shows a sequence in which V_{DDH} is raised after V_{DD} and CLKIN begins to toggle as V_{DDH} rises.

Table 9. System Clock Parameters

Characteristic	Min	Max	Unit
Phase jitter between BCLK and CLKIN	—	0.3	ns
CLKIN frequency	20	see Table 8	MHz
CLKIN slope	—	3	ns
CLKIN period jitter ¹	—	150	ps
CLKIN jitter spectrum	150	—	KHz
PLL input clock (after predivider)	20	100	MHz
PLL output frequency (VCO output)	800		MHz
• 300 MHz core		1200	MHz
• 400 MHz core		1600	MHz
• 500 MHz core		2000	MHz
CLKOUT frequency jitter ¹	—	200	ps
CLKOUT phase jitter ¹ with CLKIN phase jitter of ± 100 ps.	—	500	ps
Notes: 1. Peak-to-peak. 2. Not tested. Guaranteed by design.			

2.5.4 Reset Timing

The MSC8122 has several inputs to the reset logic:

- Power-on reset ($\overline{\text{PORESET}}$)
- External hard reset ($\overline{\text{HRESET}}$)
- External soft reset ($\overline{\text{SRESET}}$)
- Software watchdog reset
- Bus monitor reset
- Host reset command through JTAG

All MSC8122 reset sources are fed into the reset controller, which takes different actions depending on the source of the reset. The reset status register indicates the most recent sources to cause a reset. **Table 10** describes the reset sources.

Table 10. Reset Sources

Name	Direction	Description
Power-on reset ($\overline{\text{PORESET}}$)	Input	Initiates the power-on reset flow that resets the MSC8122 and configures various attributes of the MSC8122. On $\overline{\text{PORESET}}$, the entire MSC8122 device is reset. SPLI states is reset, $\overline{\text{HRESET}}$ and $\overline{\text{SRESET}}$ are driven, the SC140 extended cores are reset, and system configuration is sampled. The clock mode (MODCK bits), reset configuration mode, boot mode, Chip ID, and use of either a DSI 64 bits port or a System Bus 64 bits port are configured only when $\overline{\text{PORESET}}$ is asserted.
External hard reset ($\overline{\text{HRESET}}$)	Input/ Output	Initiates the hard reset flow that configures various attributes of the MSC8122. While $\overline{\text{HRESET}}$ is asserted, $\overline{\text{SRESET}}$ is also asserted. $\overline{\text{HRESET}}$ is an open-drain pin. Upon hard reset, $\overline{\text{HRESET}}$ and $\overline{\text{SRESET}}$ are driven, the SC140 extended cores are reset, and system configuration is sampled. The most configurable features are reconfigured. These features are defined in the 32-bit hard reset configuration word described in <i>Hard Reset Configuration Word</i> section of the <i>Reset</i> chapter in the <i>MSC8122 Reference Manual</i> .
External soft reset ($\overline{\text{SRESET}}$)	Input/ Output	Initiates the soft reset flow. The MSC8122 detects an external assertion of $\overline{\text{SRESET}}$ only if it occurs while the MSC8122 is not asserting reset. $\overline{\text{SRESET}}$ is an open-drain pin. Upon soft reset, $\overline{\text{SRESET}}$ is driven, the SC140 extended cores are reset, and system configuration is maintained.
Software watchdog reset	Internal	When the MSC8122 watchdog count reaches zero, a software watchdog reset is signalled. The enabled software watchdog event then generates an internal hard reset sequence.
Bus monitor reset	Internal	When the MSC8122 bus monitor count reaches zero, a bus monitor hard reset is asserted. The enabled bus monitor event then generates an internal hard reset sequence.
Host reset command through the TAP	Internal	When a host reset command is written through the Test Access Port (TAP), the TAP logic asserts the soft reset signal and an internal soft reset sequence is generated.

2.5.4.3 Reset Timing Tables

Table 12 and **Figure 9** describe the reset timing for a reset configuration write through the direct slave interface (DSI) or through the system bus.

Table 12. Timing for a Reset Configuration Write through the DSI or System Bus

No.	Characteristics	Expression	Min	Max	Unit
1	Required external $\overline{\text{PORESET}}$ duration minimum <ul style="list-style-type: none"> CLKIN = 20 MHz CLKIN = 100 MHz (300 MHz core) CLKIN = 133 MHz (400 MHz core) CLKIN = 166 MHz (500 MHz core) 	$16/\text{CLKIN}$	800 160 120 96	— — — —	ns ns ns ns
2	Delay from deassertion of external $\overline{\text{PORESET}}$ to deassertion of internal $\overline{\text{PORESET}}$ <ul style="list-style-type: none"> CLKIN = 20 MHz to 166 MHz 	$1024/\text{CLKIN}$	6.17	51.2	μs
3	Delay from de-assertion of internal $\overline{\text{PORESET}}$ to SPL lock <ul style="list-style-type: none"> CLKIN = 20 MHz (RDF = 1) CLKIN = 100 MHz (RDF = 1) (300 MHz core) CLKIN = 133 MHz (RDF = 2) (400 MHz core) CLKIN = 166 MHz (RDF = 2) (500 MHz core) 	$6400/(\text{CLKIN}/\text{RDF})$ (PLL reference clock-division factor)	320 64 96 77	320 64 96 77	μs μs μs μs
5	Delay from SPL lock to $\overline{\text{HRESET}}$ deassertion <ul style="list-style-type: none"> REFCLK = 40 MHz to 166 MHz 	$512/\text{REFCLK}$	3.08	12.8	μs
6	Delay from SPL lock to $\overline{\text{SRESET}}$ deassertion <ul style="list-style-type: none"> REFCLK = 40 MHz to 166 MHz 	$515/\text{REFCLK}$	3.10	12.88	μs
7	Setup time from assertion of $\overline{\text{RSTCONF}}$, CNFGS, DSISYNC, DSI64, CHIP_ID[0–3], BM[0–2], SWTE, and MODCK[1–2] before deassertion of $\overline{\text{PORESET}}$		3	—	ns
8	Hold time from deassertion of $\overline{\text{PORESET}}$ to deassertion of $\overline{\text{RSTCONF}}$, CNFGS, DSISYNC, DSI64, CHIP_ID[0–3], BM[0–2], SWTE, and MODCK[1–2]		5	—	ns

Note: Timings are not tested, but are guaranteed by design.

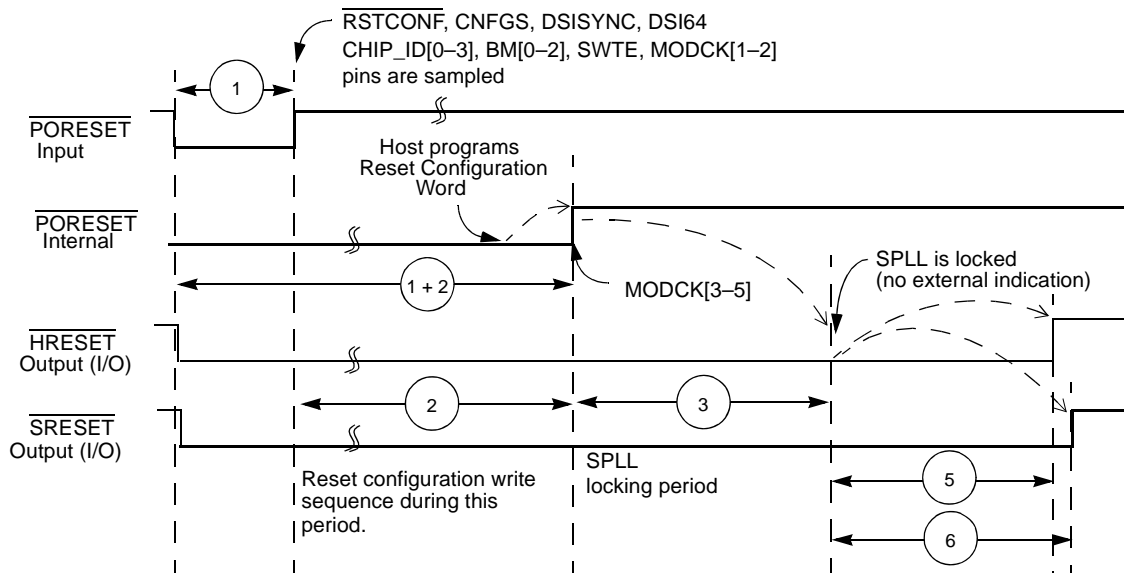


Figure 9. Timing Diagram for a Reset Configuration Write

2.5.5 System Bus Access Timing

2.5.5.1 Core Data Transfers

Generally, all MSC8122 bus and system output signals are driven from the rising edge of the reference clock (REFCLK). The REFCLK is the CLKIN signal. Memory controller signals, however, trigger on four points within a REFCLK cycle. Each cycle is divided by four internal ticks: T1, T2, T3, and T4. T1 always occurs at the rising edge of REFCLK (and T3 at the falling edge), but the spacing of T2 and T4 depends on the PLL clock ratio selected, as **Table 13** shows.

Table 13. Tick Spacing for Memory Controller Signals

BCLK/SC140 clock	Tick Spacing (T1 Occurs at the Rising Edge of REFCLK)		
	T2	T3	T4
1:4, 1:6, 1:8, 1:10	1/4 REFCLK	1/2 REFCLK	3/4 REFCLK
1:3	1/6 REFCLK	1/2 REFCLK	4/6 REFCLK
1:5	2/10 REFCLK	1/2 REFCLK	7/10 REFCLK

Figure 10 is a graphical representation of **Table 13**.

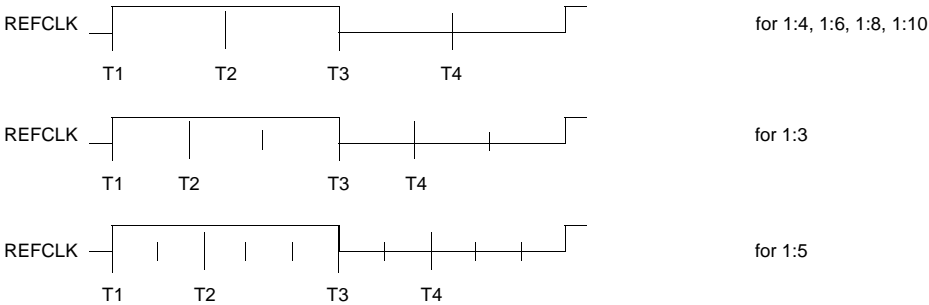


Figure 10. Internal Tick Spacing for Memory Controller Signals

The UPM machine and GPCM machine outputs change on the internal tick selected by the memory controller configuration. The AC timing specifications are relative to the internal tick. SDRAM machine outputs change only on the REFCLK rising edge.

Table 14. AC Timing for SIU Inputs

No.	Characteristic	Value for Bus Speed in MHz				Units
		Ref = CLKIN			Ref = CLKOUT	
		1.1 V	1.2 V	1.2 V	1.2 V	
		100/ 133	133	166	133	
10	Hold time for all signals after the 50% level of the REFCLK rising edge	0.5	0.5	0.5	0.5	ns
11a	$\overline{\text{ARTRY}}/\overline{\text{ABB}}$ set-up time before the 50% level of the REFCLK rising edge	3.1	3.0	3.0	3.0	ns
11b	$\overline{\text{DBG}}/\overline{\text{DBB}}/\overline{\text{BG}}/\overline{\text{BR}}/\overline{\text{TC}}$ set-up time before the 50% level of the REFCLK rising edge	3.6	3.3	3.3	3.3	ns
11c	$\overline{\text{AACK}}$ set-up time before the 50% level of the REFCLK rising edge	3.0	2.9	2.9	2.9	ns
11d	$\overline{\text{TA}}/\overline{\text{TEA}}/\overline{\text{PSDVAL}}$ set-up time before the 50% level of the REFCLK rising edge • Data-pipeline mode • Non-pipeline mode	3.5	3.4	3.4	3.4	ns
		4.4	4.0	4.0	4.0	ns
12	Data bus set-up time before REFCLK rising edge in Normal mode • Data-pipeline mode • Non-pipeline mode	1.9	1.8	1.7	1.8	ns
		4.2	4.0	4.0	4.0	ns
13 ¹	Data bus set-up time before the 50% level of the REFCLK rising edge in ECC and PARITY modes • Data-pipeline mode • Non-pipeline mode	2.0	2.0	2.0	2.0	ns
		8.2	7.3	7.3	7.3	ns
14 ¹	DP set-up time before the 50% level of the REFCLK rising edge • Data-pipeline mode • Non-pipeline mode	2.0	2.0	2.0	2.0	ns
		7.9	6.1	6.1	6.1	ns
15a	$\overline{\text{TS}}$ and Address bus set-up time before the 50% level of the REFCLK rising edge • Extra cycle mode (SIUBCR[EXDD] = 0) • No extra cycle mode (SIUBCR[EXDD] = 1)	4.2	3.8	3.8	3.8	ns
		5.5	5.0	5.0	5.0	ns
15b	Address attributes: $\overline{\text{TT}}/\overline{\text{TBST}}/\overline{\text{TSZ}}/\overline{\text{GBL}}$ set-up time before the 50% level of the REFCLK rising edge • Extra cycle mode (SIUBCR[EXDD] = 0) • No extra cycle mode (SIUBCR[EXDD] = 1)	3.7	3.5	3.5	3.5	ns
		4.8	4.4	4.4	4.4	ns
16	PUPMWAIT signal set-up time before the 50% level of the REFCLK rising edge	3.7	3.7	3.7	3.7	ns
17	$\overline{\text{IRQx}}$ setup time before the 50% level; of the REFCLK rising edge ³	4.0	4.0	4.0	4.0	ns
18	$\overline{\text{IRQx}}$ minimum pulse width ³	6.0 + T_{REFCLK}	6.0 + T_{REFCLK}	6.0 + T_{REFCLK}	6.0 + T_{REFCLK}	ns
Notes: 1. Timings specifications 13 and 14 in non-pipeline mode are more restrictive than MSC8102 timings. 2. Values are measured from the 50% TTL transition level relative to the 50% level of the REFCLK rising edge. 3. Guaranteed by design.						

Table 15. AC Timing for SIU Outputs

No.	Characteristic	Value for Bus Speed in MHz ³				Units
		Ref = CLKIN			Ref = CLKOUT	
		1.1 V	1.2 V	1.2 V	1.2 V	
		100/133	133	166	100/133	
30 ²	Minimum delay from the 50% level of the REFCLK for all signals	0.9	0.8	0.8	1.0	ns
31	$\overline{\text{PSDVAL}}/\overline{\text{TEA}}/\overline{\text{TA}}$ max delay from the 50% level of the REFCLK rising edge	6.0	4.9	4.9	5.8	ns
32a	Address bus max delay from the 50% level of the REFCLK rising edge • Multi-master mode (SIUBCR[EBM] = 1) • Single-master mode (SIUBCR[EBM] = 0)	6.4	5.5	5.5	6.4	ns
		5.3	4.2	3.9	5.1	ns
32b	Address attributes: $\overline{\text{TT}}[0-1]/\overline{\text{TBST}}/\overline{\text{TSZ}}/\overline{\text{GBL}}$ max delay from the 50% level of the REFCLK rising edge	6.4	5.1	5.1	6.0	ns
32c	Address attributes: $\overline{\text{TT}}[2-4]/\overline{\text{TC}}$ max delay from the 50% level of the REFCLK rising edge	6.9	5.7	5.7	6.6	ns
32d	$\overline{\text{BADDR}}$ max delay from the 50% level of the REFCLK rising edge	5.2	4.2	4.2	5.1	ns
33a	Data bus max delay from the 50% level of the REFCLK rising edge • Data-pipeline mode • Non-pipeline mode	4.8	3.9	3.7	4.8	ns
		7.1	6.1	6.1	7.0	ns
33b	DP max delay from the 50% level of the REFCLK rising edge • Data-pipeline mode • Non-pipeline mode	6.0	5.3	5.3	6.2	ns
		7.5	6.5	6.5	7.4	ns
34	Memory controller signals/ $\overline{\text{ALE}}/\overline{\text{CS}}[0-4]$ max delay from the 50% level of the REFCLK rising edge	5.1	4.2	3.9	5.1	ns
35a	$\overline{\text{DBG}}/\overline{\text{BG}}/\overline{\text{BR}}/\overline{\text{DBB}}$ max delay from the 50% level of the REFCLK rising edge	6.0	4.7	4.7	5.6	ns
35b	$\overline{\text{AACK}}/\overline{\text{ABB}}/\overline{\text{TS}}/\overline{\text{CS}}[5-7]$ max delay from the 50% level of the REFCLK rising edge	5.5	4.5	4.5	5.4	ns
Notes: <ol style="list-style-type: none"> 1. Values are measured from the 50% level of the REFCLK rising edge to the 50% signal level and assume a 20 pF load except where otherwise specified. 2. Except for specification 30, which is specified for a 10 pF load, all timings in this table are specified for a 20 pF load. Decreasing the load results in a timing decrease at the rate of 0.3 ns per 5 pF decrease in load. Increasing the load results in a timing increase at the rate of 0.15 ns per 5 pF increase in load. 3. The maximum bus frequency depends on the mode: <ul style="list-style-type: none"> • In 60x-compatible mode connected to another MSC8122 device, the frequency is determined by adding the input and output longest timing values, which results in the total delay for 20 pF output capacitance. You must also account for other influences that can affect timing, such as on-board clock skews, on-board noise delays, and so on. • In single-master mode, the frequency depends on the timing of the devices connected to the MSC8122. • To achieve maximum performance on the bus in single-master mode, disable the $\overline{\text{DBB}}$ signal by writing a 1 to the SIUMCR[BDD] bit. See the SIU chapter in the <i>MSC8122 Reference Manual</i> for details. 						

2.5.5.2 CLKIN to CLKOUT Skew

Table 17 describes the CLKOUT-to-CLKIN skew timing.

Table 16. CLKOUT Skew

No.	Characteristic	Min ¹	Max ¹	Units
20	Rise-to-rise skew <ul style="list-style-type: none">V_{DD} = 1.1 VV_{DD} = 1.2 V	0.0	0.95	ns
		0.0	0.85	ns
21	Fall-to-fall skew <ul style="list-style-type: none">V_{DD} = 1.1 VV_{DD} = 1.2 V	−1.5	1.0	ns
		−0.8	1.0	ns
22	CLKOUT phase (1.2 V, 133 MHz) <ul style="list-style-type: none">Phase highPhase low	2.8	—	ns
		2.8	—	ns
23	CLKOUT phase (1.1 V, 133 MHz) <ul style="list-style-type: none">Phase highPhase low	2.2	—	ns
		2.2	—	ns
24	CLKOUT phase (1.1 V, 100 MHz) <ul style="list-style-type: none">Phase highPhase low	3.3	—	ns
		3.3	—	ns
Notes:	<div><div>1.</div><div>A positive number indicates that CLKOUT precedes CLKIN, A negative number indicates that CLKOUT follows CLKIN.</div></div> <div><div>2.</div><div>Skews are measured in clock mode 29, with a CLKIN:CLKOUT ratio of 1:1. The same skew is valid for all clock modes.</div></div> <div><div>3.</div><div>CLKOUT skews are measured using a load of 10 pF.</div></div> <div><div>4.</div><div>CLKOUT skews and phase are not measured for 500/166 Mhz parts because these parts only use CLKIN mode.</div></div>			

For designs that use the CLKOUT synchronization mode, use the skew values listed in Table 16 to adjust the rise-to-fall timing values specified for CLKIN synchronization. Figure 12 shows the relationship between the CLKOUT and CLKIN timings.

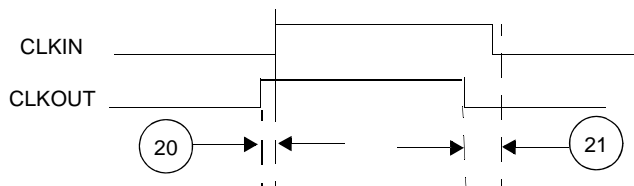


Figure 12. CLKOUT and CLKIN Signals.

2.5.5.3 DMA Data Transfers

Table 17 describes the DMA signal timing.

Table 17. DMA Signals

No.	Characteristic	Ref = CLKIN		Ref = CLKOUT (1.2 V only)		Units
		Min	Max	Min	Max	
37	DREQ set-up time before the 50% level of the falling edge of REFCLK	5.0	—	5.0	—	ns
38	DREQ hold time after the 50% level of the falling edge of REFCLK	0.5	—	0.5	—	ns
39	DONE set-up time before the 50% level of the rising edge of REFCLK	5.0	—	5.0	—	ns
40	DONE hold time after the 50% level of the rising edge of REFCLK	0.5	—	0.5	—	ns
41	DACK/DRACK/DONE delay after the 50% level of the REFCLK rising edge	0.5	7.5	0.5	8.4	ns

The DREQ signal is synchronized with REFCLK. To achieve fast response, a synchronized peripheral should assert DREQ according to the timings in Table 17. Figure 13 shows synchronous peripheral interaction.

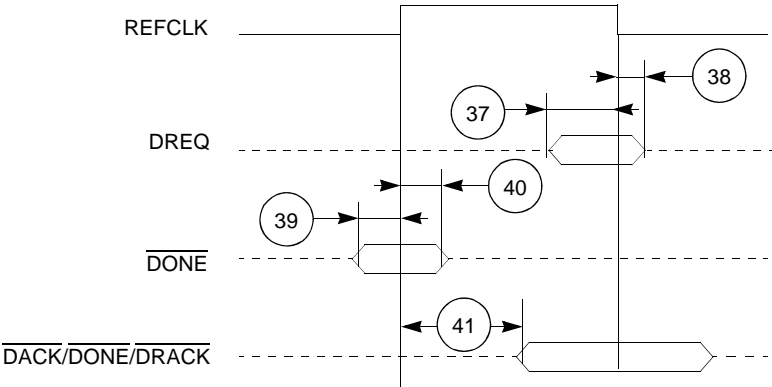
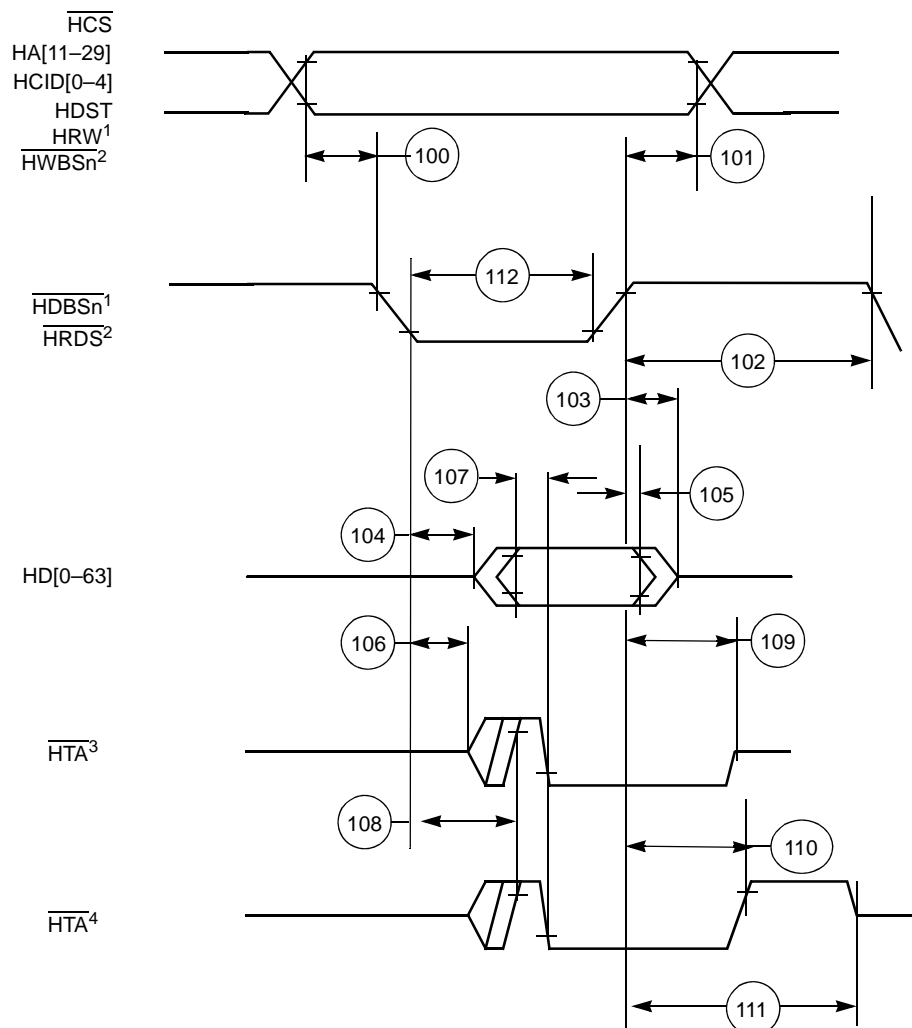


Figure 13. DMA Signals

Figure 14 shows DSI asynchronous read signals timing.



- Notes:**
1. Used for single-strobe mode access.
 2. Used for dual-strobe mode access.
 3. HTA released at logic 0 (DCR[HTAAD] = 0) at end of access; used with pull-down implementation.
 4. HTA released at logic 1 (DCR[HTAAD] = 1) at end of access; used with pull-up implementation.

Figure 14. Asynchronous Single- and Dual-Strobe Modes Read Timing Diagram

2.5.6.2 DSI Synchronous Mode

Table 19. DSI Inputs in Synchronous Mode

No.	Characteristic	Expression	1.1 V Core		1.2 V Core		Units
			Min	Max	Min	Max	
120	HCLKIN cycle time ^{1,2}	HTC	10.0	55.6	10.0	55.6	ns
121	HCLKIN high pulse width	$(0.5 \pm 0.1) \times \text{HTC}$	4.0	33.3	4.0	33.3	ns
122	HCLKIN low pulse width	$(0.5 \pm 0.1) \times \text{HTC}$	4.0	33.3	4.0	33.3	ns
123	HA[11–29] inputs set-up time	—	1.2	—	1.2	—	ns
124	HD[0–63] inputs set-up time	—	0.6	—	0.4	—	ns
125	HCID[0–4] inputs set-up time	—	1.3	—	1.3	—	ns
126	All other inputs set-up time	—	1.2	—	1.2	—	ns
127	All inputs hold time	—	1.5	—	1.5	—	ns

Notes:

- Values are based on a frequency range of 18–100 MHz.
- Refer to **Table 7** for HCLKIN frequency limits.

Table 20. DSI Outputs in Synchronous Mode

No.	Characteristic	1.1 V Core		1.2 V Core		Units
		Min	Max	Min	Max	
128	HCLKIN high to HD[0–63] output active	2.0	—	2.0	—	ns
129	HCLKIN high to HD[0–63] output valid	—	7.6	—	6.3	ns
130	HD[0–63] output hold time	1.7	—	1.7	—	ns
131	HCLKIN high to HD[0–63] output high impedance	—	8.3	—	7.6	ns
132	HCLKIN high to HTA output active	2.2	—	2.0	—	ns
133	HCLKIN high to HTA output valid	—	7.4	—	5.9	ns
134	HTA output hold time	1.7	—	1.7	—	ns
135	HCLKIN high to HTA high impedance	—	7.5	—	6.3	ns

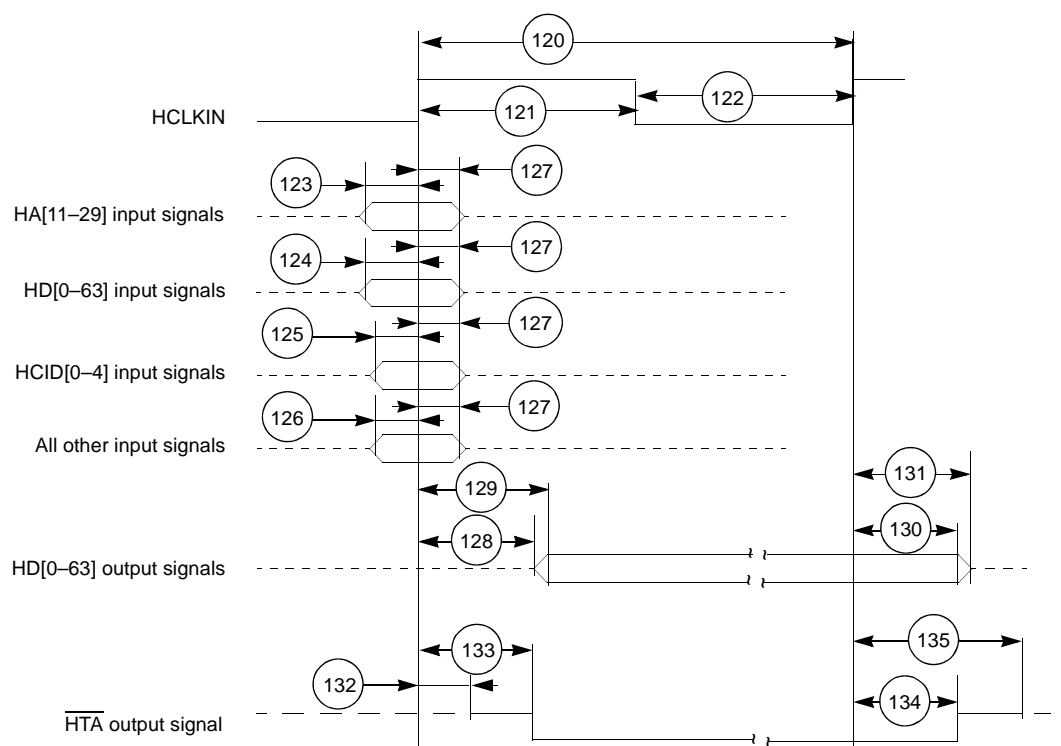


Figure 17. DSI Synchronous Mode Signals Timing Diagram

2.5.10.4 SMII Mode

Table 27. SMII Mode Signal Timing

No.	Characteristics	Min	Max	Unit
808	ETHSYNC_IN, ETHRXD to ETHCLOCK rising edge set-up time	1.0	—	ns
809	ETHCLOCK rising edge to ETHSYNC_IN, ETHRXD hold time	1.0	—	ns
810	ETHCLOCK rising edge to ETHSYNC, ETHTXD output delay	1.5 ¹ 1.5 ¹	6.0 ² 5.0 ²	ns ns
Notes: 1. Measured using a 5 pF load. 2. Measured using a 15 pF load.				

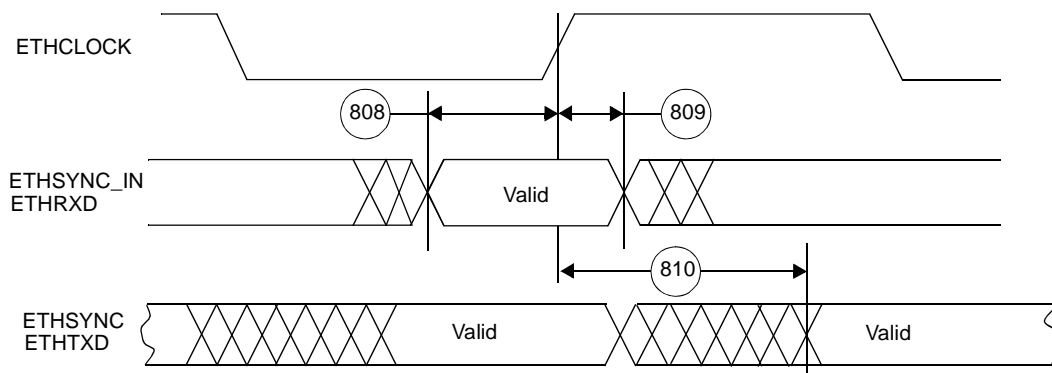


Figure 26. SMII Mode Signal Timing

2.5.11 GPIO Timing

Table 28. GPIO Timing

No.	Characteristics	Ref = CLKIN		Ref = CLKOUT (1.2 V only)		Unit
		Min	Max	Min	Max	
601	REFCLK edge to GPIO out valid (GPIO out delay time)	—	6.1	—	6.9	ns
602	REFCLK edge to GPIO out not valid (GPIO out hold time)	1.1	—	1.3	—	ns
603	REFCLK edge to high impedance on GPIO out	—	5.4	—	6.2	ns
604	GPIO in valid to REFCLK edge (GPIO in set-up time)	3.5	—	3.7	—	ns
605	REFCLK edge to GPIO in not valid (GPIO in hold time)	0.5	—	0.5	—	ns

